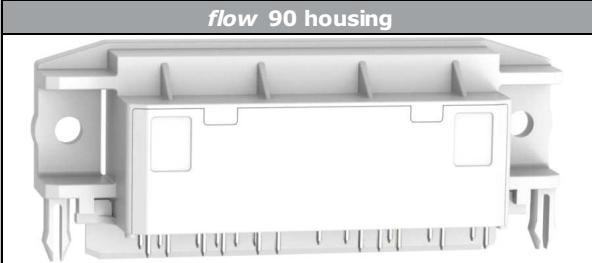
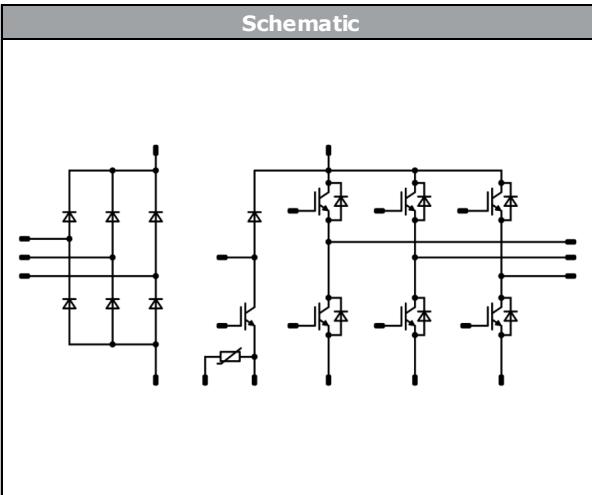




10-R112PMA025M7-P630A70

datasheet

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flow 90PIM 1		1200 V / 25 A
Features		
	<ul style="list-style-type: none">• IGBT M7 with low V_{CEsat} and improved EMC behavior• Open emitter configuration• Supports design with 90° angle• Clip or screw-on heat sink mounting• Built-in NTC	
Target applications		Schematic
	<ul style="list-style-type: none">• Industrial Drives	
Types		
	<ul style="list-style-type: none">• 10-R112PMA025M7-P630A70	

Maximum Ratings

 $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Rectifier Diode				
Peak Repetitive Reverse Voltage	V_{RRM}		1600	V
Continuous (direct) forward current	I_F		25	A
Surge (non-repetitive) forward current	I_{FSM}	50 Hz Single Half Sine Wave $t_p = 10 \text{ ms}$	200	A
Surge current capability	I^2t	$T_j = 150^\circ\text{C}$	200	A^2s
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	44	W
Maximum Junction Temperature	T_{jmax}		150	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current	I_C		25	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	50	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	82	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$
Inverter Diode				
Peak repetitive reverse voltage	V_{RRM}		1200	V
Continuous (direct) forward current	I_F		25	A
Repetitive peak forward current	I_{FRM}	T_j limited by T_{jmax}	50	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	62	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$
Brake Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current	I_C		15	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	30	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	60	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$
Brake Diode				
Peak repetitive reverse voltage	V_{RRM}		1200	V
Continuous (direct) forward current	I_F		15	A
Repetitive peak forward current	I_{FRM}	T_j limited by T_{jmax}	30	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	45	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25 \text{ } ^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
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Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...($T_{\text{jmax}} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V	
		AC Voltage	$t_p = 1 \text{ min}$	2500	V	
Creepage distance				min. 12,7	mm	
Clearance				11,84	mm	
Comparative Tracking Index				> 200		

*100 % tested in production



10-R112PMA025M7-P630A70

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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V]	V_{CE} [V]	I_c [A]	I_D [A]	T_j [°C]	Min	Typ	Max	
			V_{GS} [V]	V_{DS} [V]	I_F [A]	I_F [A]					

Rectifier Diode

Static

Forward voltage	V_F				25	25 125		1,22 1,21	1,75		V
Reverse leakage current	I_r			1600		25 145			50 1100		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,59			K/W
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10-R112PMA025M7-P630A70

datasheet

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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V]	V_{CE} [V]	I_c [A]	I_D [A]	T_1 [°C]	Min	Typ	Max	
			V_{GS} [V]	V_{DS} [V]	I_F [A]	I_F [A]					

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0025	25	5,4	6	6,6	V
Collector-emitter saturation voltage	V_{CESat}		15		25	125 150		1,65 1,89 1,95	2,15	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			70	µA
Gate-emitter leakage current	I_{GES}		20	0		25			500	nA
Internal gate resistance	r_g							none		Ω
Input capacitance	C_{ies}		0	10	25			4800		pF
Output capacitance	C_{oes}							170		
Reverse transfer capacitance	C_{res}							57		
Gate charge	Q_g		15	600	25	25		180		nC

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,16		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{goff} = 16 \Omega$ $R_{gon} = 16 \Omega$	± 15	600	25	25		147		ns
Rise time	t_r					125		149		
Turn-off delay time	$t_{d(off)}$					150		145		
Fall time	t_f	$Q_{fFWD} = 2,5 \mu\text{C}$ $Q_{fFWD} = 3,9 \mu\text{C}$ $Q_{fFWD} = 4,3 \mu\text{C}$	± 15	600	25	25		29		mWs
Turn-on energy (per pulse)	E_{on}					125		33		
Turn-off energy (per pulse)	E_{off}					150		34		
						25		171		
						125		191		
						150		196		
						25		95		
						125		110		
						150		115		
						25		2,06		
						125		2,66		
						150		2,82		
						25		1,67		
						125		2,18		
						150		2,29		



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_1 [°C]	Min	Typ	Max		

Inverter Diode

Static

Forward voltage	V_F				25	25 125 150		1,63 1,70 1,69	2,1	V
Reverse leakage current	I_R			1200		25			35	µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,54		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 645 \text{ A/}\mu\text{s}$ $di/dt = 673 \text{ A/}\mu\text{s}$ $di/dt = 633 \text{ A/}\mu\text{s}$	± 15	600	25	25		21		A
Reverse recovery time	t_{rr}					125		23		
						150		23		
Recovered charge	Q_r					25		254		
Recovered charge	Q_r					125		367		ns
Recovered charge	Q_r					150		404		
Reverse recovered energy	E_{rec}					25		2,54		
Reverse recovered energy	E_{rec}					125		3,88		
Reverse recovered energy	E_{rec}					150		4,28		µC
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25		0,88		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		1,45		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		1,61		mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25		217		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		134		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		132		A/µs



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit	
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_c [A]	I_D [A]	T_j [°C]	Min	Typ	Max	

Brake Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0015	25	5,4	6	6,6	V	
Collector-emitter saturation voltage	V_{CESat}		15		15	125 150		1,70 1,95 2,01	2,15	V	
Collector-emitter cut-off current	I_{CES}		0	1200		25			60	μA	
Gate-emitter leakage current	I_{GES}		20	0		25			500	nA	
Internal gate resistance	r_g							none		Ω	
Input capacitance	C_{ies}		0	10	25			2900		pF	
Output capacitance	C_{oes}							120			
Reverse transfer capacitance	C_{res}							34			
Gate charge	Q_g		15	600	15	25		1100		nC	

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,60		K/W	
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{goff} = 32 \Omega$ $R_{gon} = 32 \Omega$	15/0	600	15	25		96		ns	
Rise time	Tr					125		85			
						150		78			
Turn-off delay time	$t_{d(off)}$	$R_{goff} = 32 \Omega$ $R_{gon} = 32 \Omega$	15/0	600	15	25		61		mWs	
						125		62			
						150		65			
Fall time	t_f	$Q_{rFWD} = 1,5 \mu\text{C}$ $Q_{rFWD} = 2,4 \mu\text{C}$ $Q_{rFWD} = 2,7 \mu\text{C}$	15/0	600	15	25		296			
Turn-on energy (per pulse)	E_{on}					125		324			
						150		331			
Turn-off energy (per pulse)	E_{off}	$Q_{rFWD} = 1,5 \mu\text{C}$ $Q_{rFWD} = 2,4 \mu\text{C}$ $Q_{rFWD} = 2,7 \mu\text{C}$	15/0	600	15	25		97			
						125		116			
						150		120			
		$Q_{rFWD} = 1,5 \mu\text{C}$ $Q_{rFWD} = 2,4 \mu\text{C}$ $Q_{rFWD} = 2,7 \mu\text{C}$	15/0	600	15	25		1,65			
						125		2,05			
						150		2,17			
		$Q_{rFWD} = 1,5 \mu\text{C}$ $Q_{rFWD} = 2,4 \mu\text{C}$ $Q_{rFWD} = 2,7 \mu\text{C}$	15/0	600	15	25		1,00			
						125		1,34			
						150		1,43			



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Brake Diode

Static

Forward voltage	V_F				15	25 125 150		1,63 1,74 1,73	2,1	V
Reverse leakage current	I_R			1200		25			30	µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						2,11		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 205 \text{ A/µs}$ $di/dt = 185 \text{ A/µs}$ $di/dt = 188 \text{ A/µs}$	15/0	600	15	25 125 150		10 11 11		A
Reverse recovery time	Tr_{rr}					25 125 150		283 420 463		ns
Recovered charge	Q_r					25 125 150		1,49 2,44 2,68		µC
Reverse recovered energy	E_{rec}					25 125 150		0,505 0,916 1,01		mWs
Peak rate of fall of recovery current	$(di_r/dt)_{max}$					25 125 150		75 51 47		A/µs

Thermistor

Rated resistance	R					25		22		kΩ
Deviation of R_{100}	$\Delta R/R$	$R_{100} = 1486 \Omega$				100	-12		+14	%
Power dissipation	P					25		200		mW
Power dissipation constant						25		2		mW/K
B-value	$B_{(25/50)}$	Tol. ±3%				25		3950		K
B-value	$B_{(25/100)}$	Tol. ±3%				25		3998		K
Vincotech NTC Reference									B	



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Rectifier Diode Characteristics

figure 1.
Typical forward characteristics

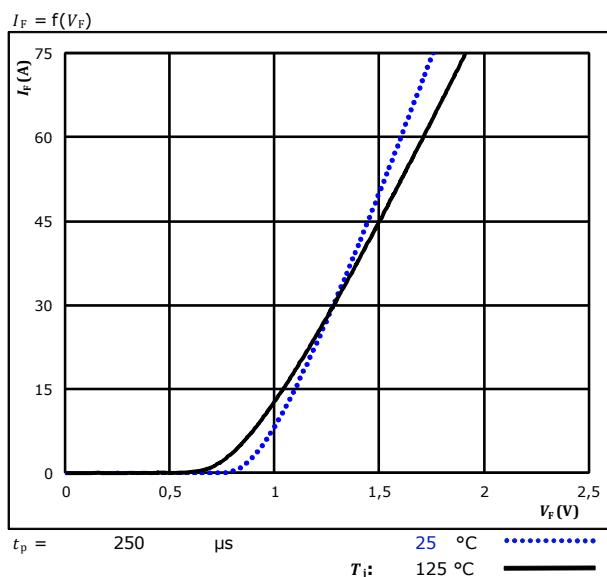
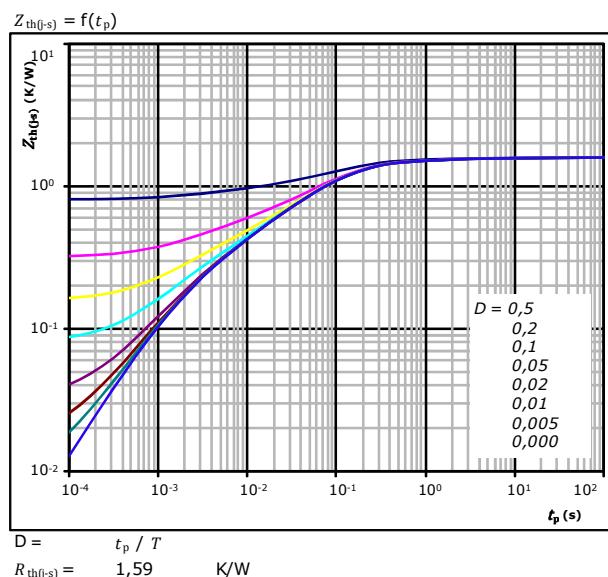


figure 2.
Transient thermal impedance as a function of pulse width



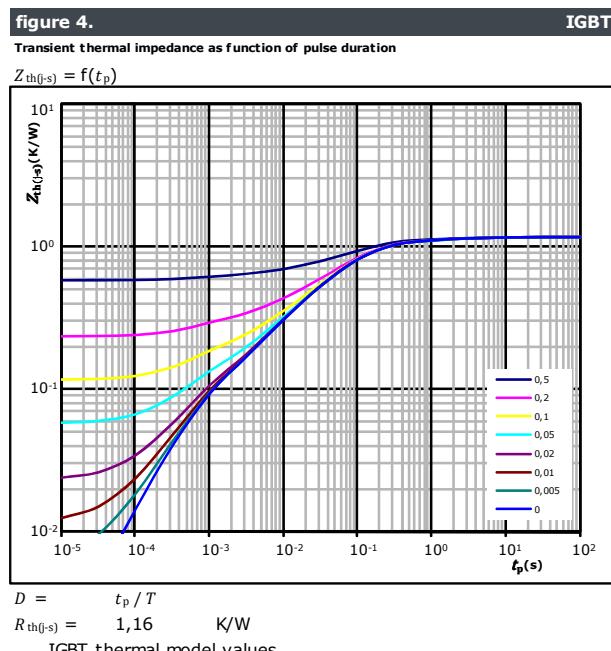
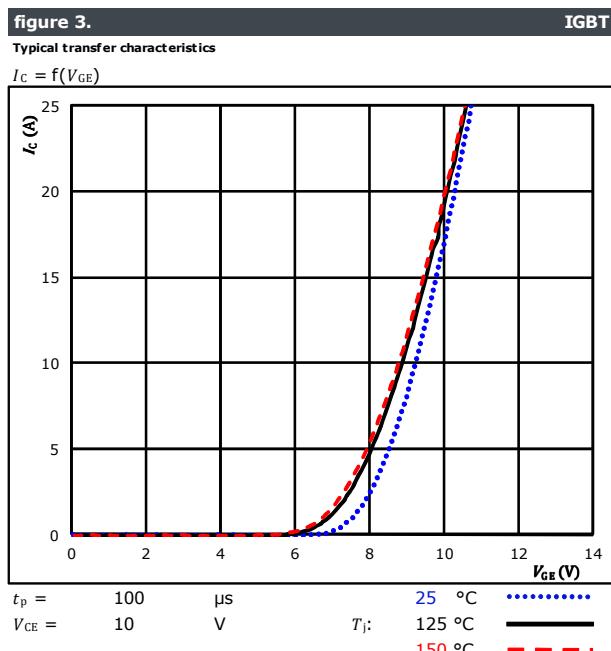
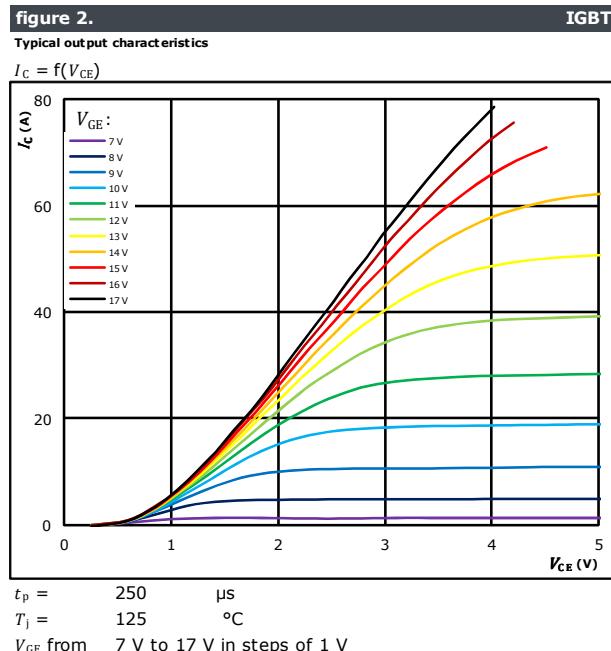
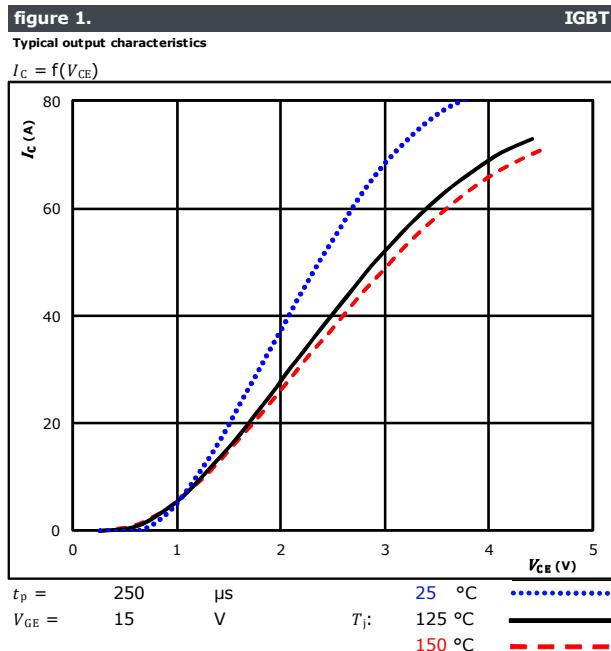
Diode thermal model values

R (K/W)	τ (s)
3,44E-02	9,66E+00
1,12E-01	1,22E+00
5,81E-01	1,45E-01
4,89E-01	5,05E-02
2,38E-01	9,26E-03
1,22E-01	1,79E-03
1,22E-01	1,79E-03
1,81E-02	7,88E-04



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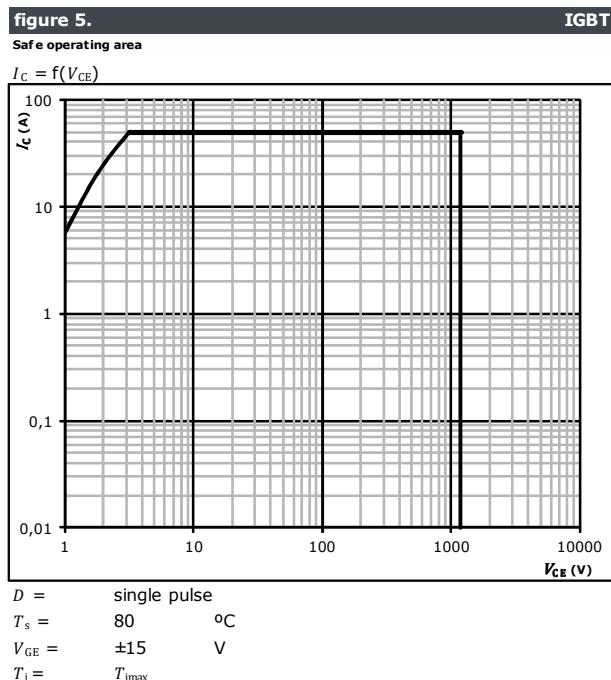
Inverter Switch Characteristics





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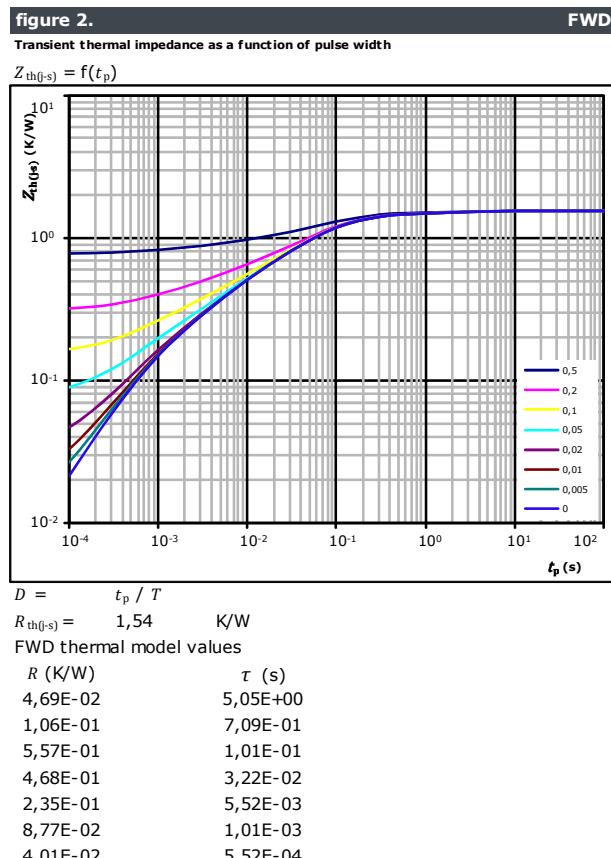
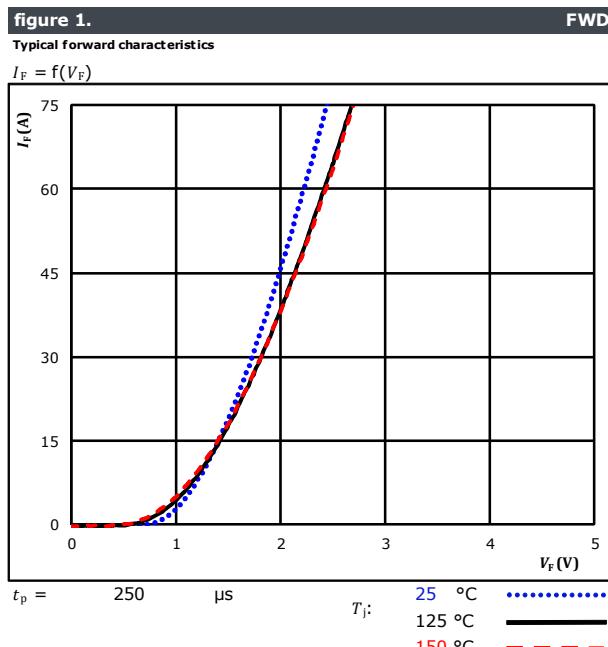
Inverter Switch Characteristics





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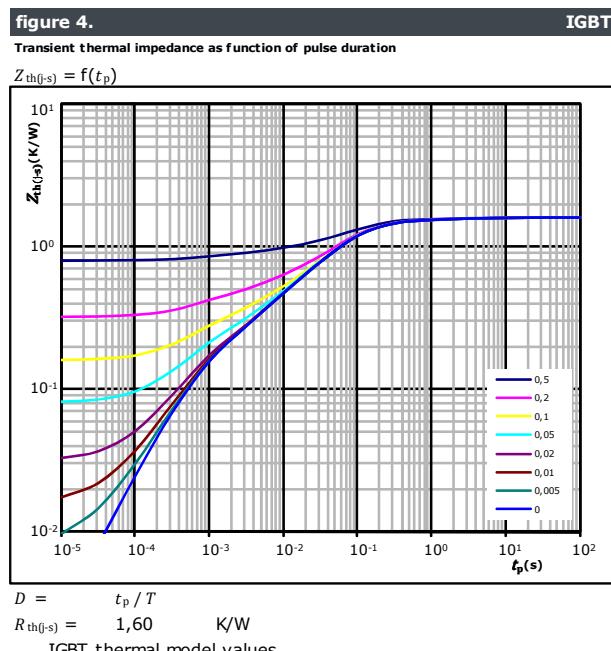
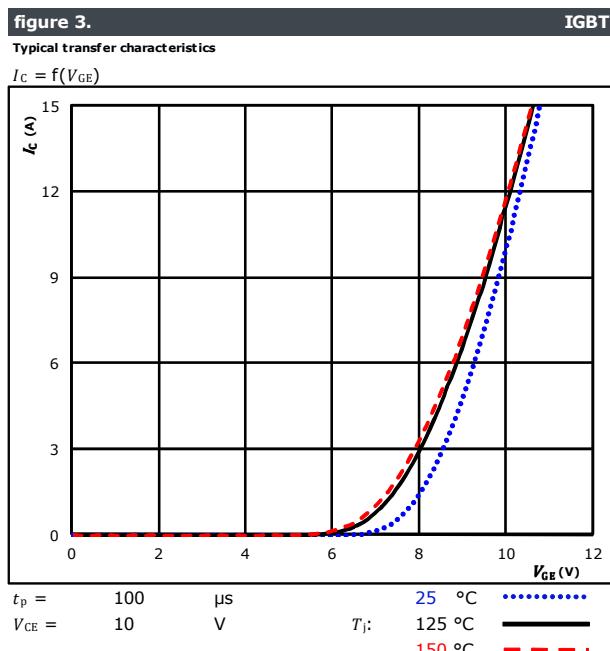
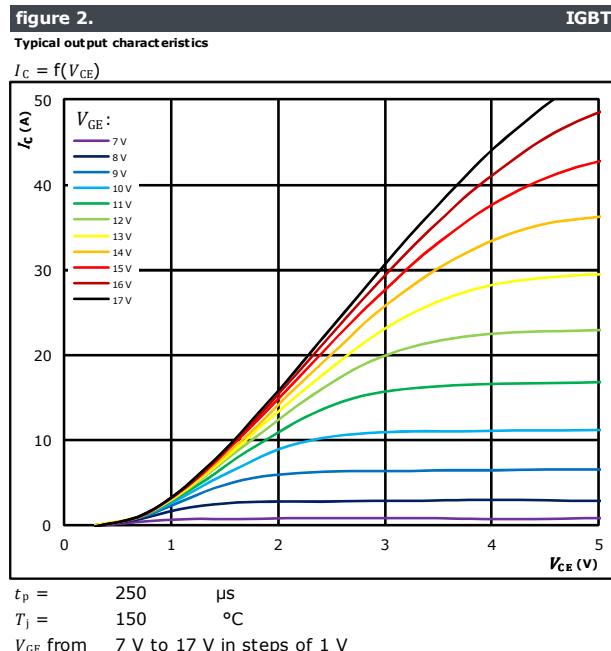
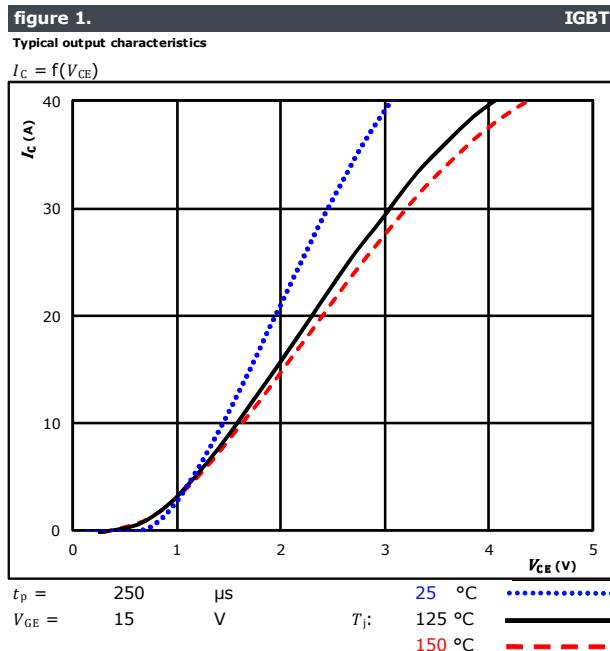
Inverter Diode Characteristics





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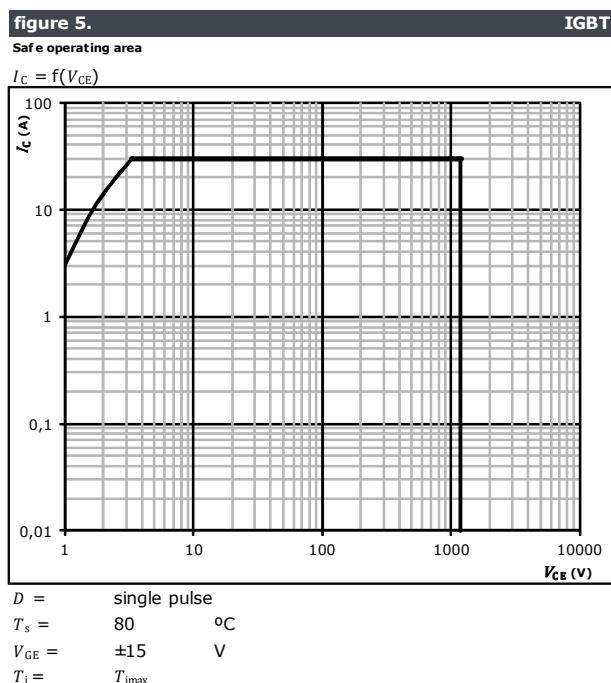
Brake Switch Characteristics





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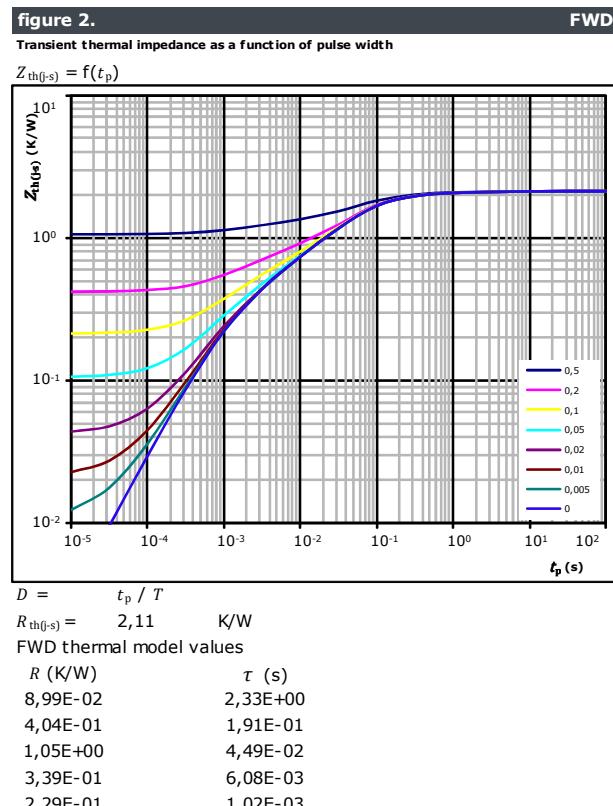
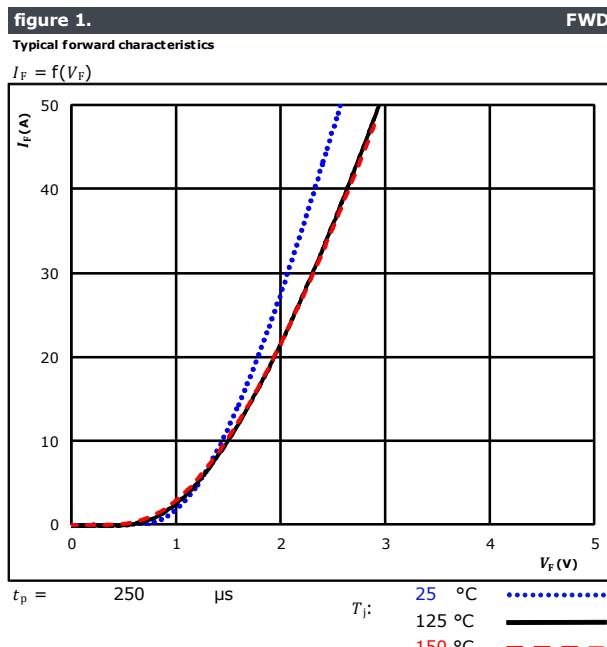
Brake Switch Characteristics



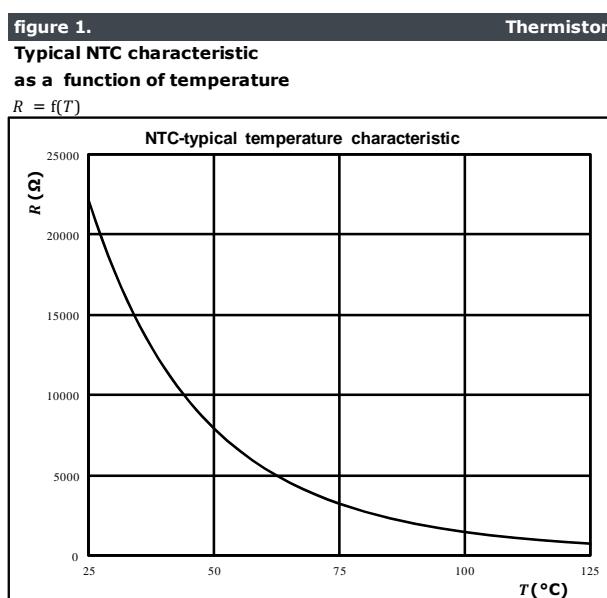


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Brake Diode Characteristics



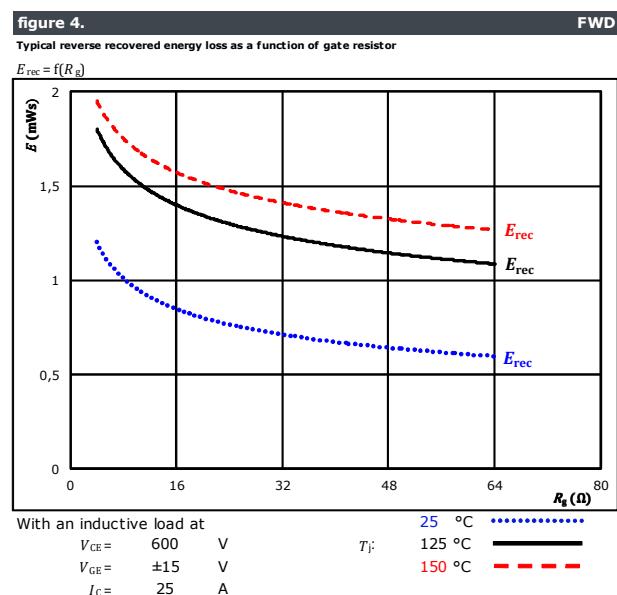
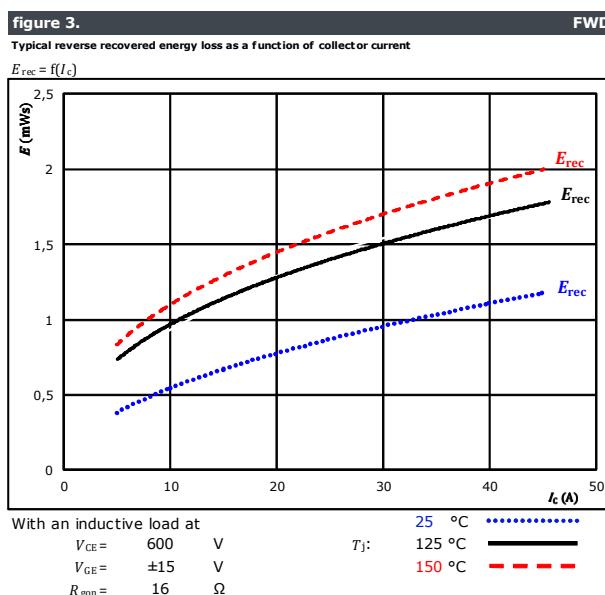
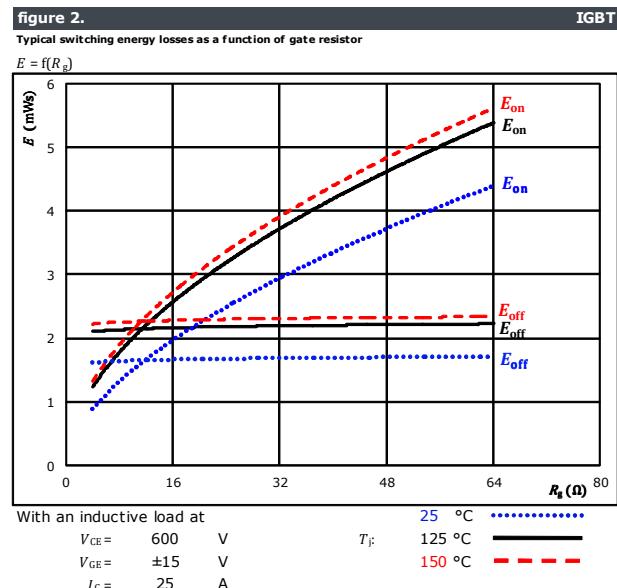
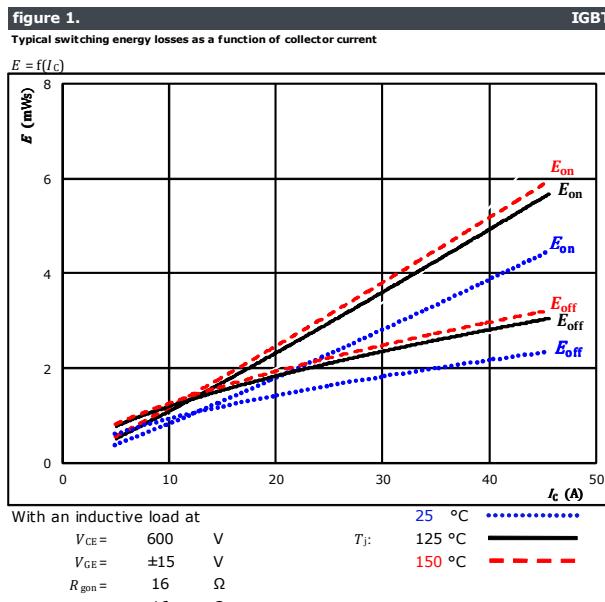
Thermistor Characteristics





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Inverter Switching Characteristics

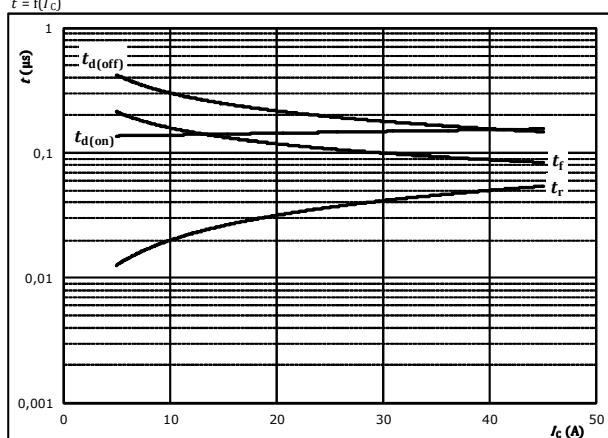




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Inverter Switching Characteristics

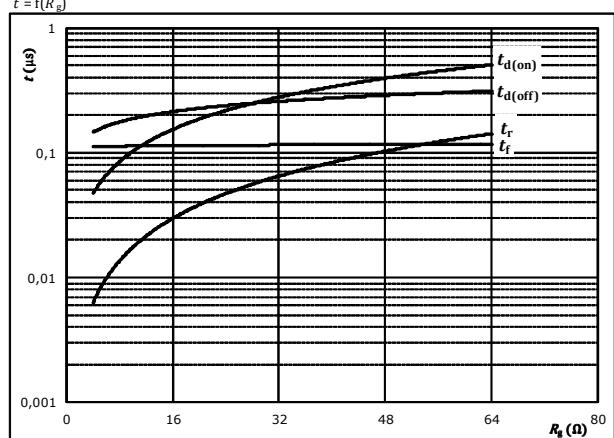
figure 5. IGBT
Typical switching times as a function of collector current
 $t = f(I_c)$



With an inductive load at

$T_J =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$R_{gon} =$	16	Ω
$R_{goff} =$	16	Ω

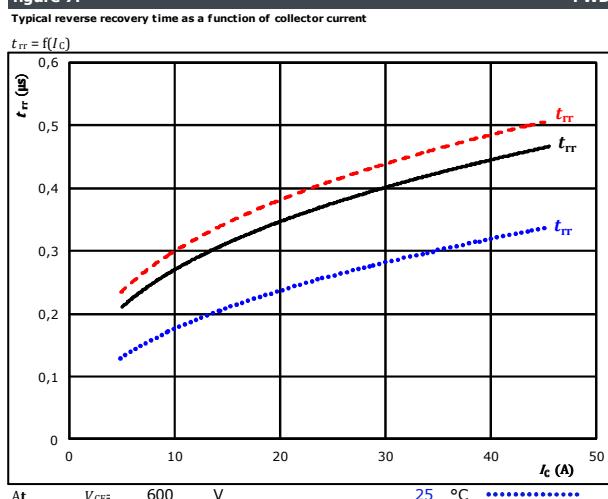
figure 6. IGBT
Typical switching times as a function of gate resistor
 $t = f(R_g)$



With an inductive load at

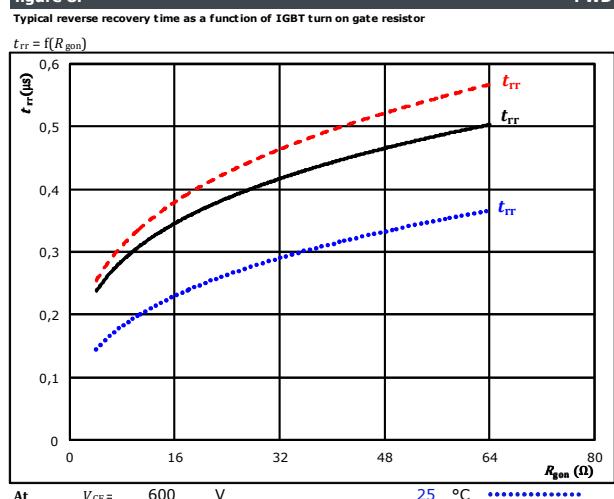
$T_J =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$I_C =$	25	A

figure 7. FWD
Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_c)$



At	$V_{CE} =$	600	V	25 °C
	$V_{GE} =$	±15	V	$T_J =$	125 °C
	$R_{gon} =$	16	Ω		150 °C

figure 8. FWD
Typical reverse recovery time as a function of IGBT turn on gate resistor
 $t_{rr} = f(R_{gon})$

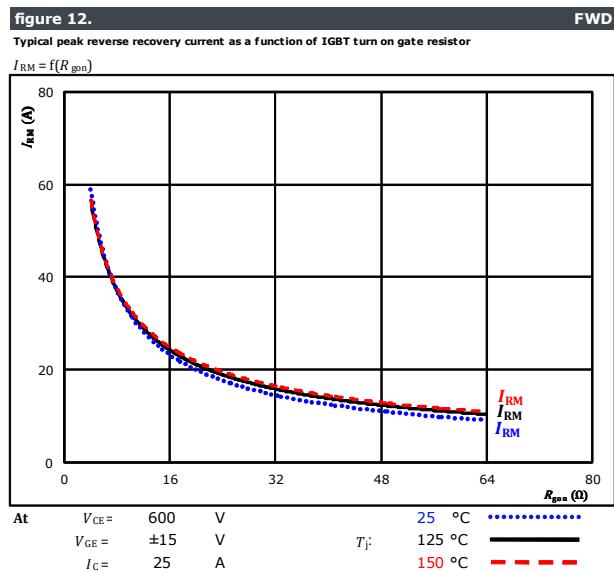
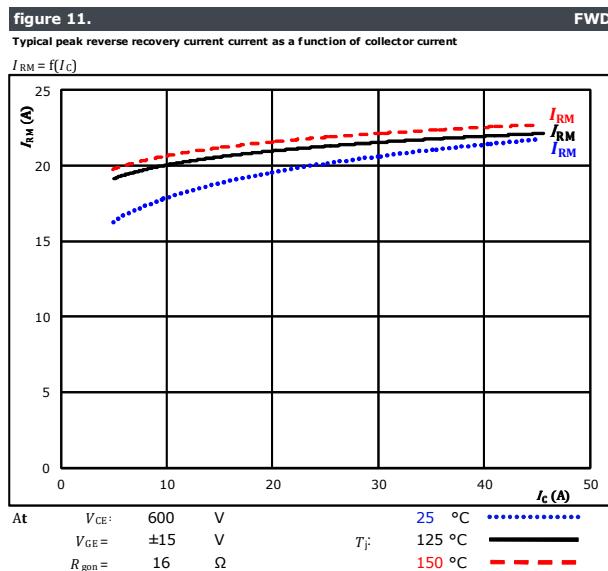
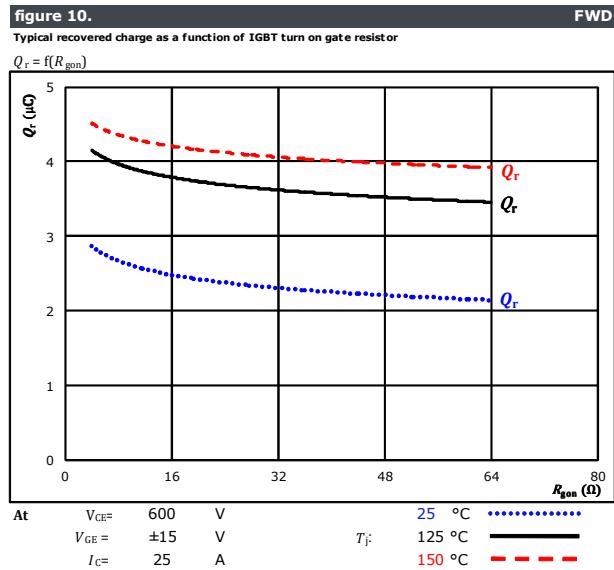
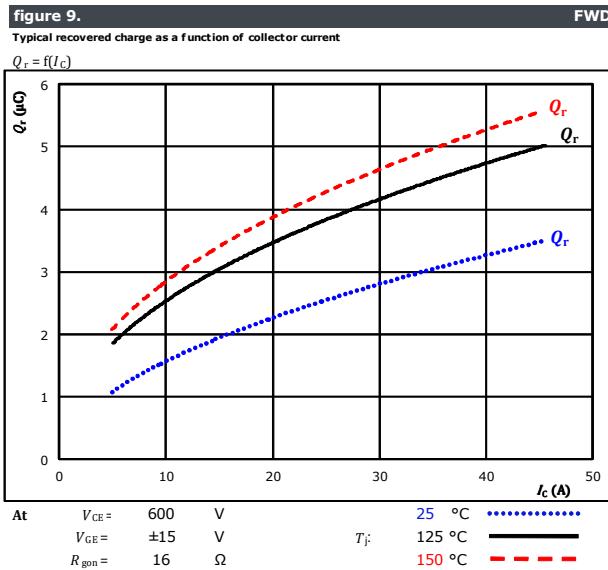


At	$V_{CE} =$	600	V	25 °C
	$V_{GE} =$	±15	V	$T_J =$	125 °C
	$I_C =$	25	A		150 °C



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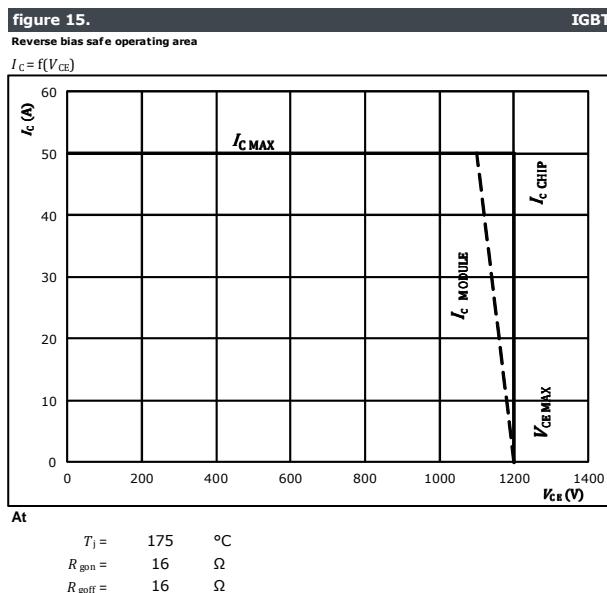
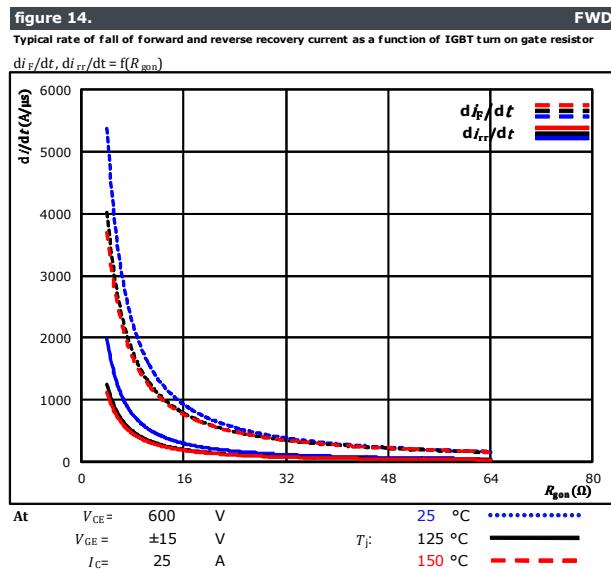
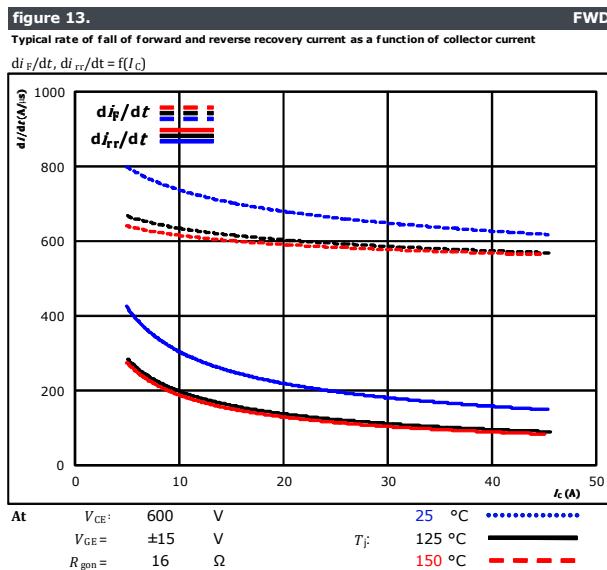
Inverter Switching Characteristics





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Inverter Switching Characteristics





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Inverter Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	16 Ω
R_{goff}	=	16 Ω

figure 1.

IGBT

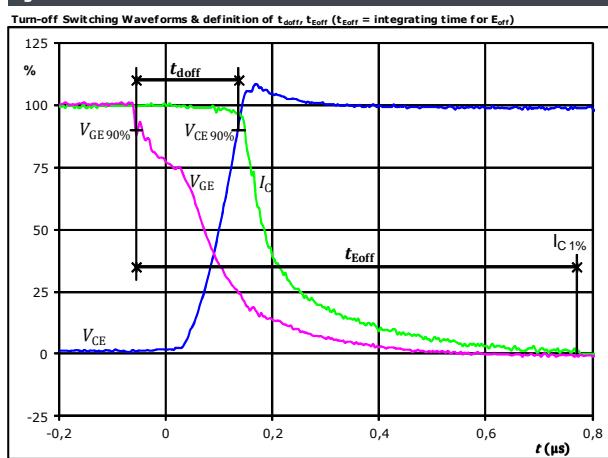


figure 3.

IGBT

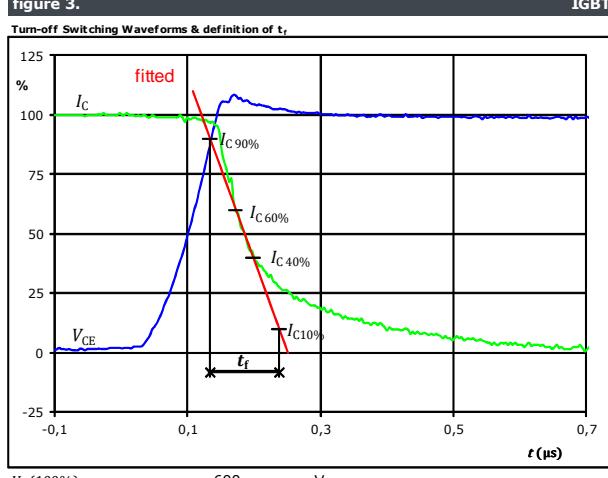


figure 2.

IGBT

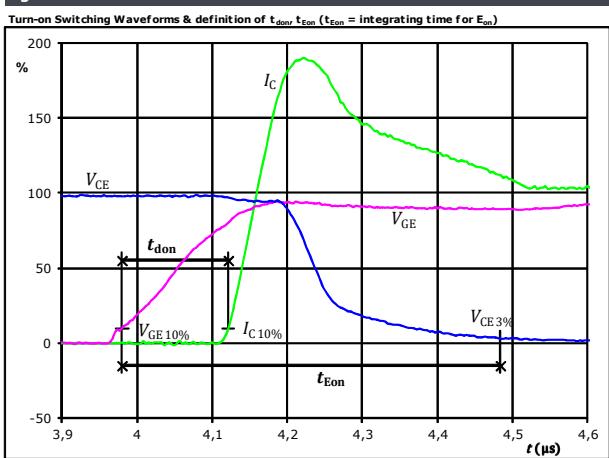
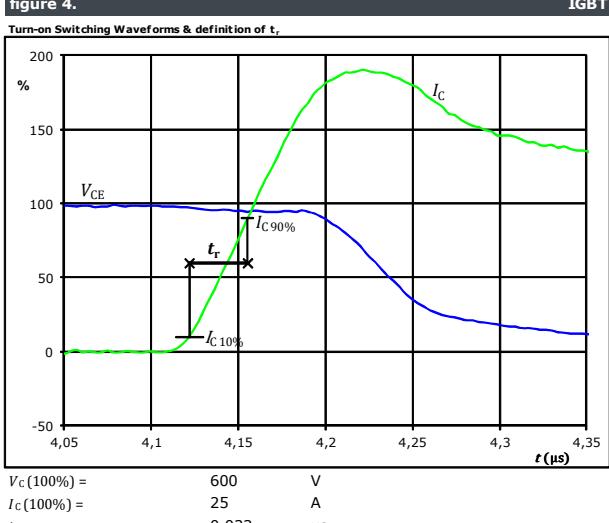


figure 4.

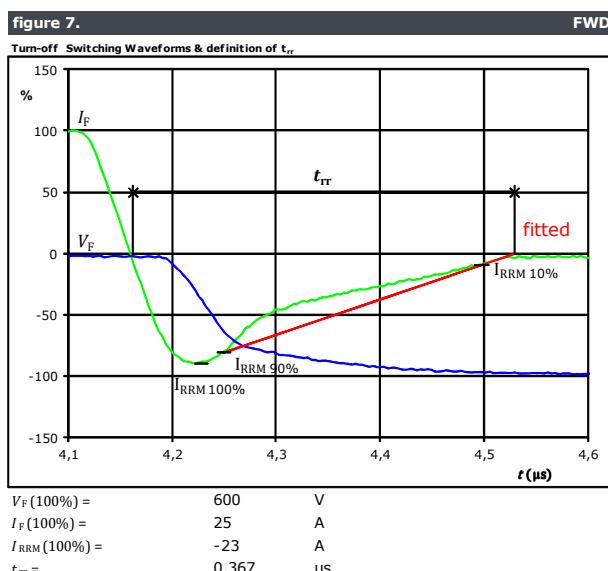
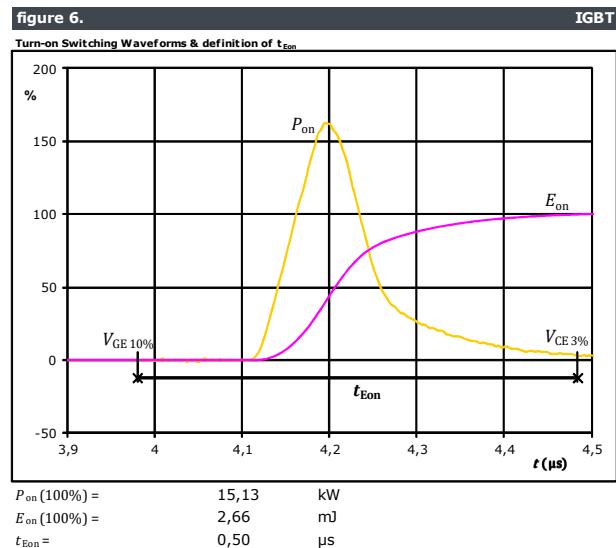
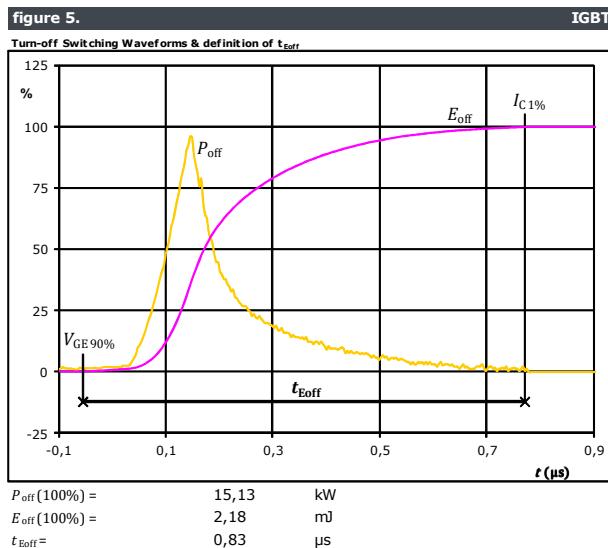
IGBT





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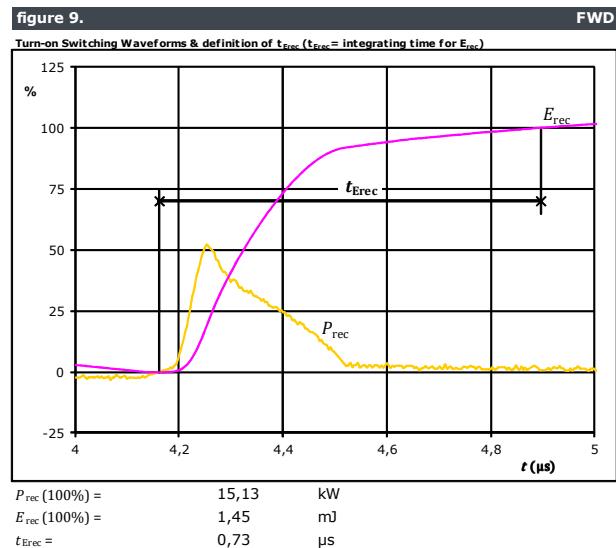
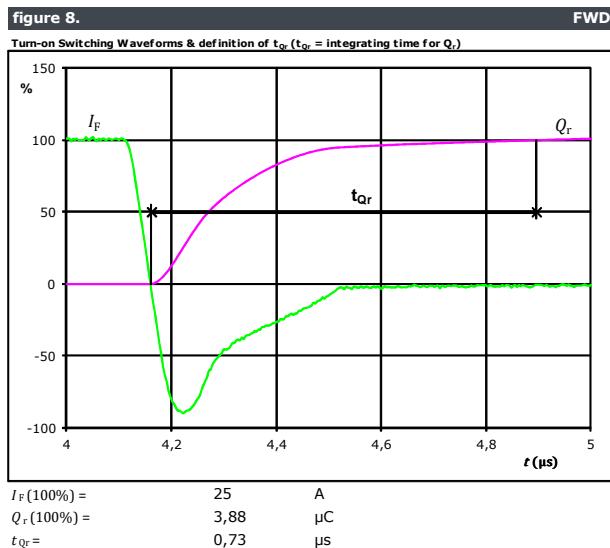
Inverter Switching Characteristics





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Inverter Switching Characteristics





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Brake Switching Characteristics

figure 1.
Typical switching energy losses as a function of collector current

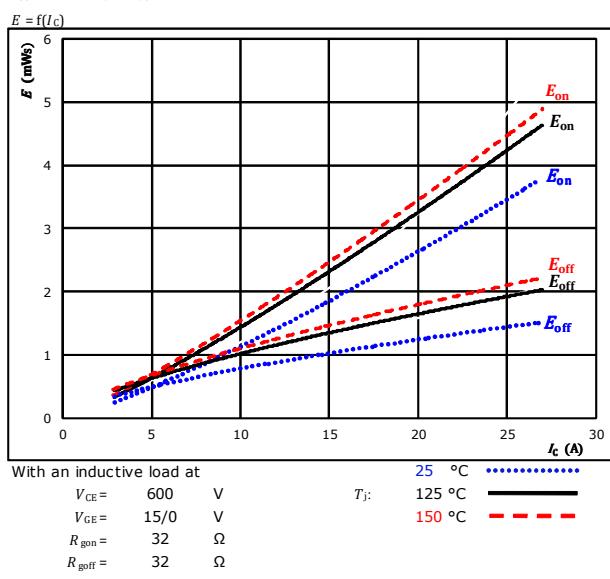


figure 2.
Typical switching energy losses as a function of gate resistor

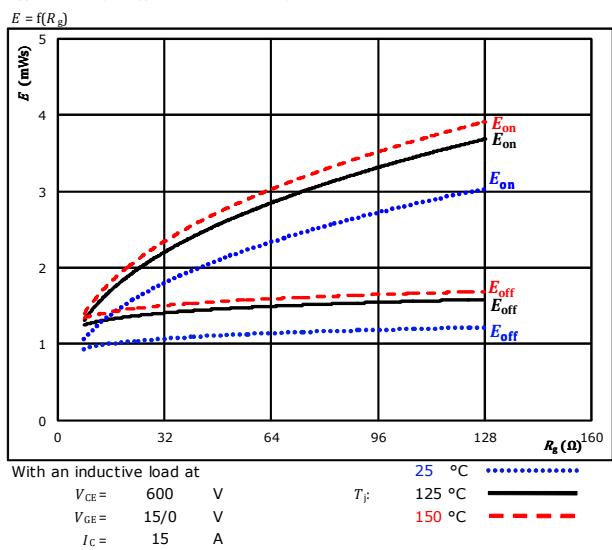


figure 3.
Typical reverse recovered energy loss as a function of collector current

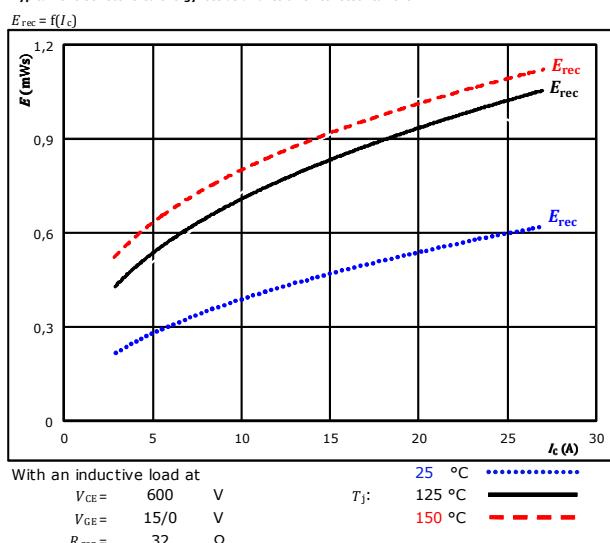
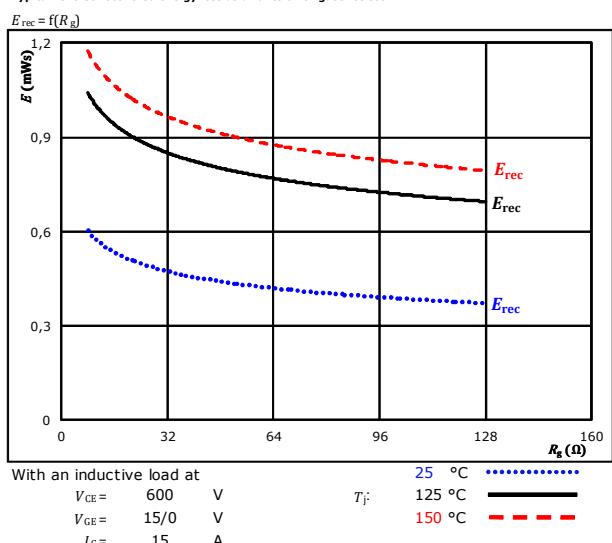


figure 4.
Typical reverse recovered energy loss as a function of gate resistor



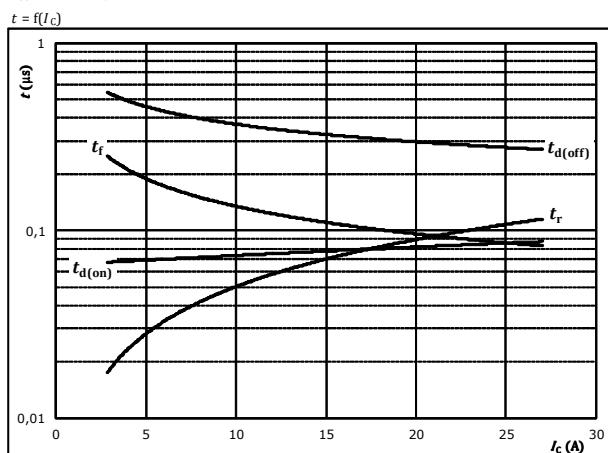


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Brake Switching Characteristics

figure 5. IGBT

Typical switching times as a function of collector current

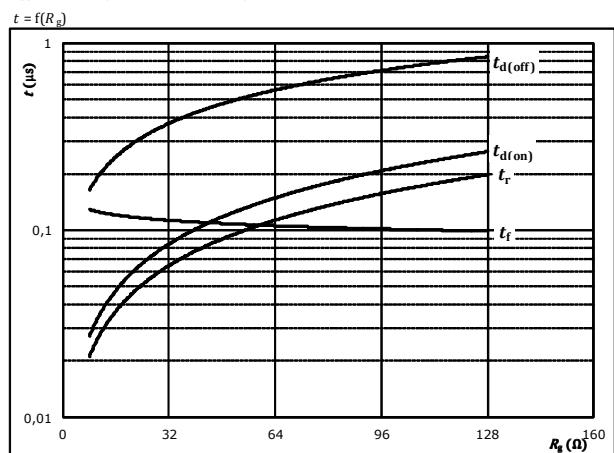


With an inductive load at

$T_J =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	15/0	V
$R_{gon} =$	32	Ω
$R_{goff} =$	32	Ω

figure 6. IGBT

Typical switching times as a function of gate resistor

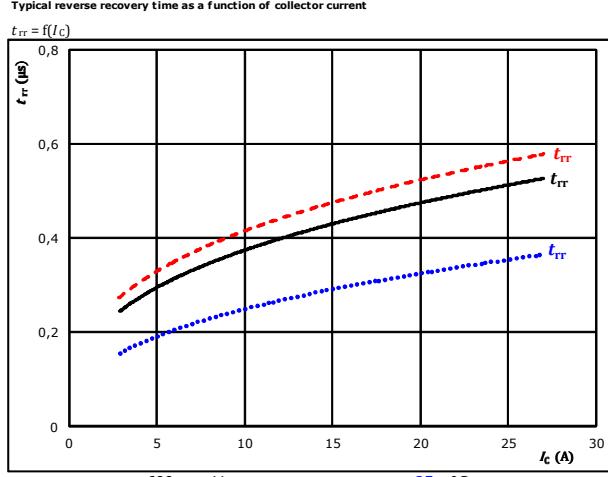


With an inductive load at

$T_J =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	15/0	V
$I_C =$	15	A

figure 7. FWD

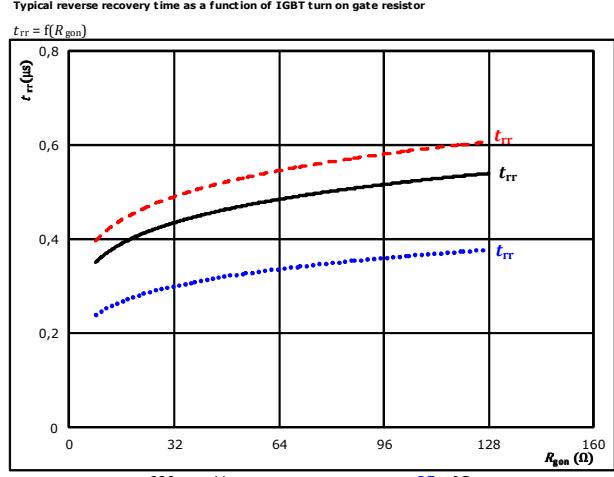
Typical reverse recovery time as a function of collector current



At	$V_{CE} =$	600	V	25	°C
	$V_{GE} =$	15/0	V	$T_J =$	125 °C	—
	$R_{gon} =$	32	Ω		150 °C	- - -

figure 8. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor

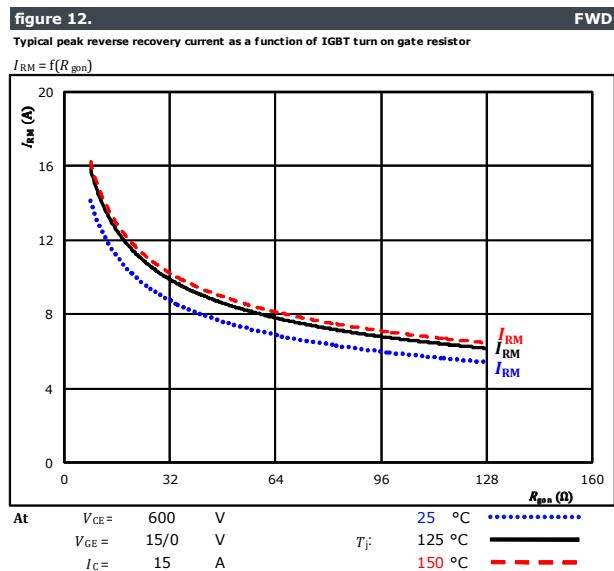
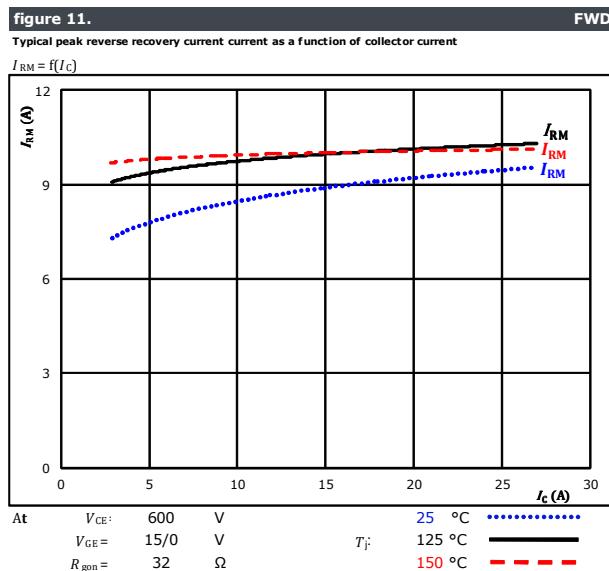
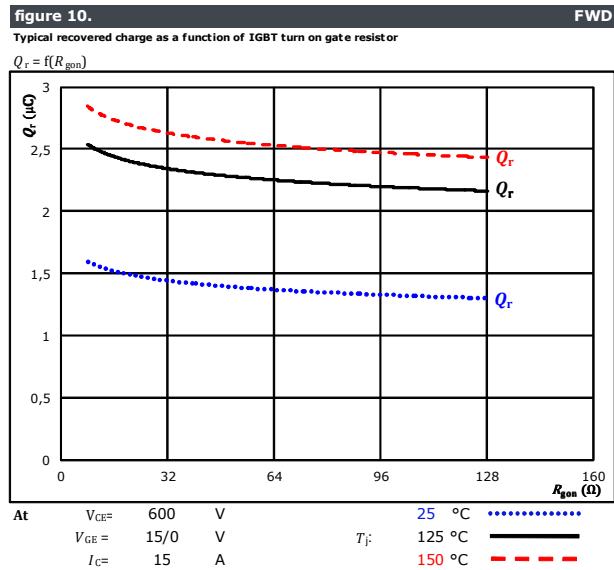
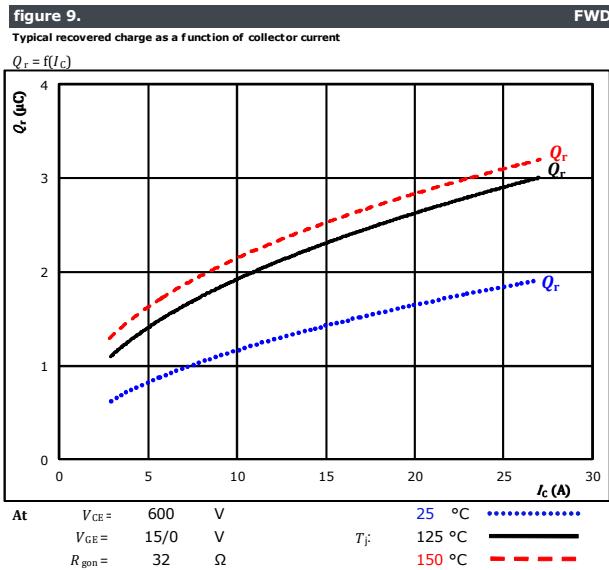


At	$V_{CE} =$	600	V	25	°C
	$V_{GE} =$	15/0	V	$T_J =$	125 °C	—
	$I_C =$	15	A		150 °C	- - -



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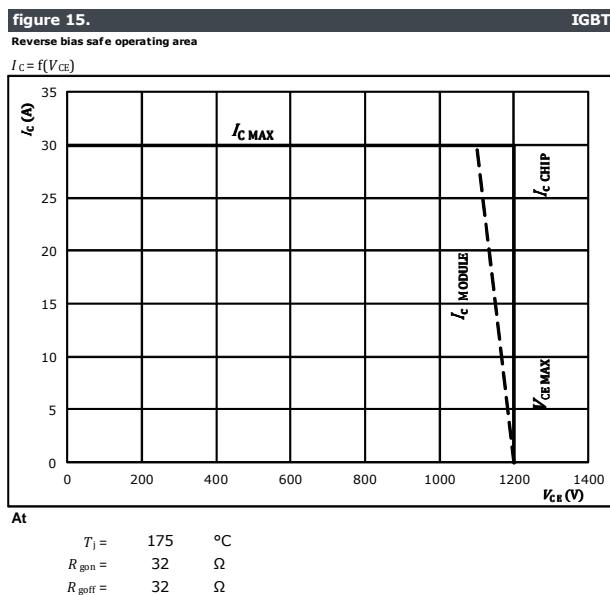
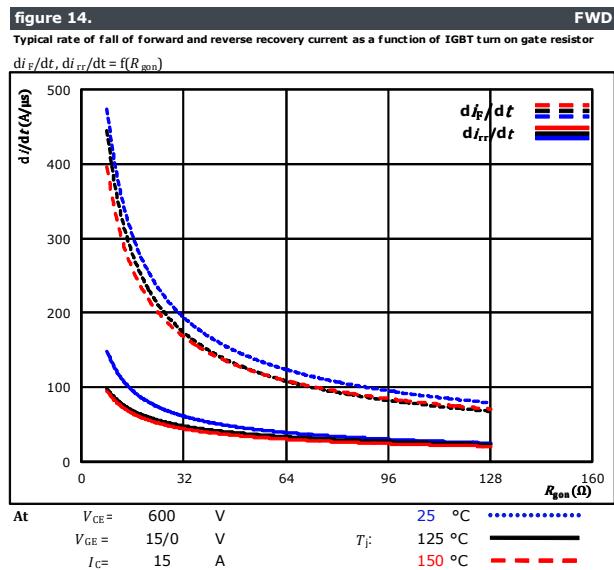
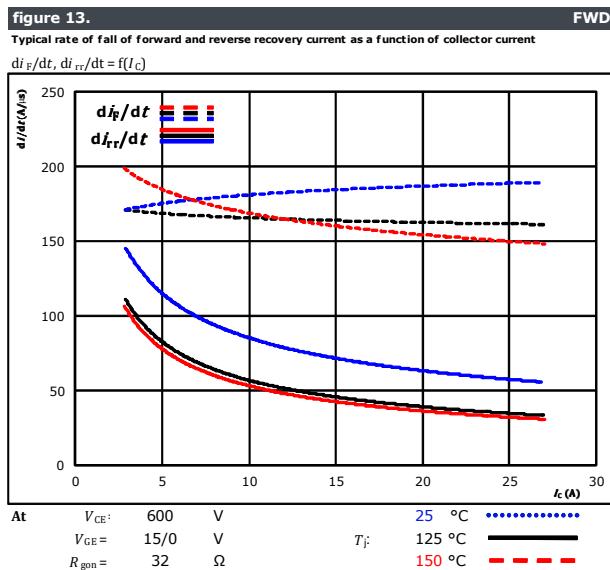
Brake Switching Characteristics





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Brake Switching Characteristics





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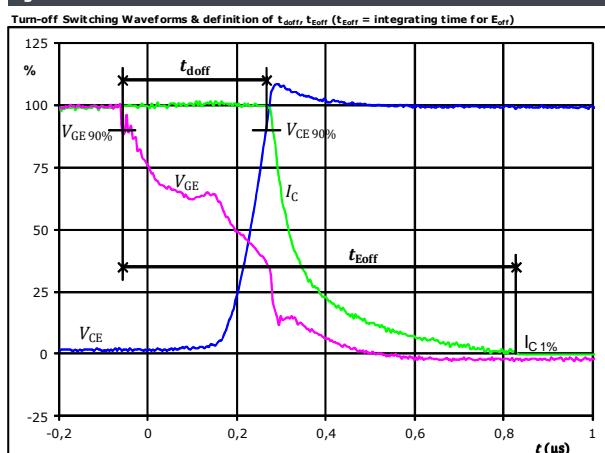
Brake Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	32 Ω
R_{goff}	=	32 Ω

figure 1.

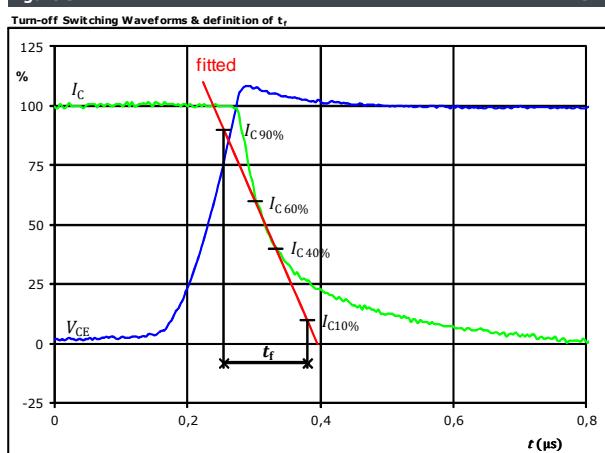
IGBT



$V_{GE\ (0\%)} =$	0	V
$V_{GE\ (100\%)} =$	15	V
$V_C\ (100\%) =$	600	V
$I_C\ (100\%) =$	15	A
$t_{doff} =$	0,324	μs
$t_{Eoff} =$	0,885	μs

figure 3.

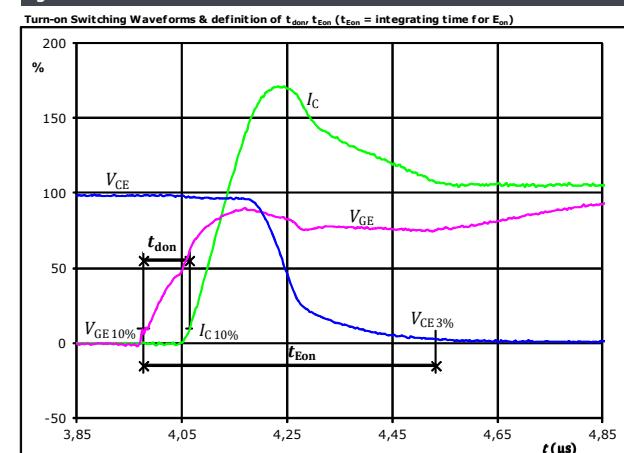
IGBT



$V_C\ (100\%) =$	600	V
$I_C\ (100\%) =$	15	A
$t_f =$	0,116	μs

figure 2.

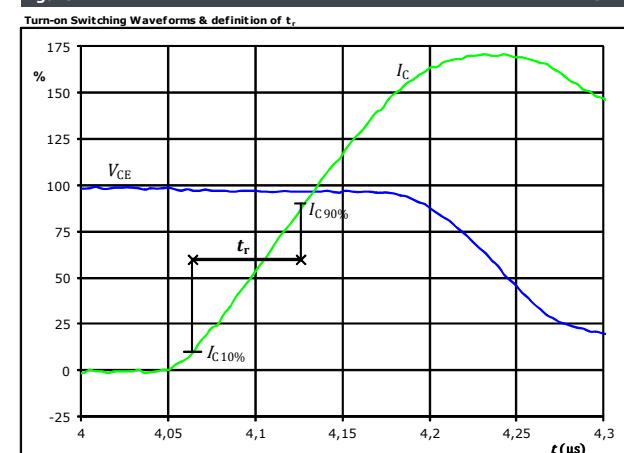
IGBT



$V_{GE\ (0\%)} =$	0	V
$V_{GE\ (100\%)} =$	15	V
$V_C\ (100\%) =$	600	V
$I_C\ (100\%) =$	15	A
$t_{don} =$	0,085	μs
$t_{Eon} =$	0,556	μs

figure 4.

IGBT

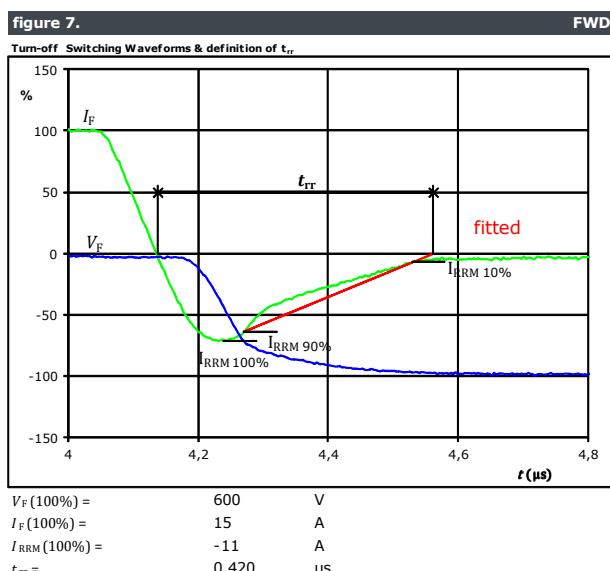
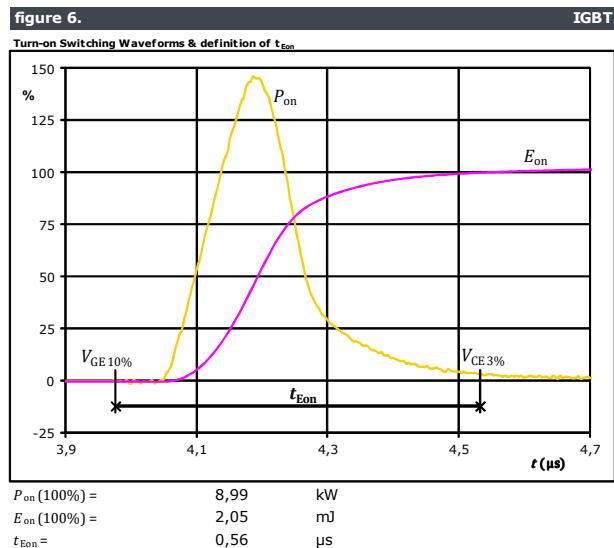
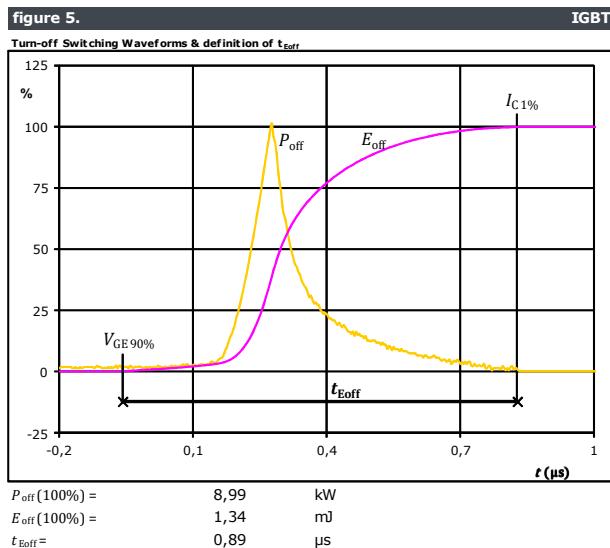


$V_C\ (100\%) =$	600	V
$I_C\ (100\%) =$	15	A
$t_r =$	0,062	μs



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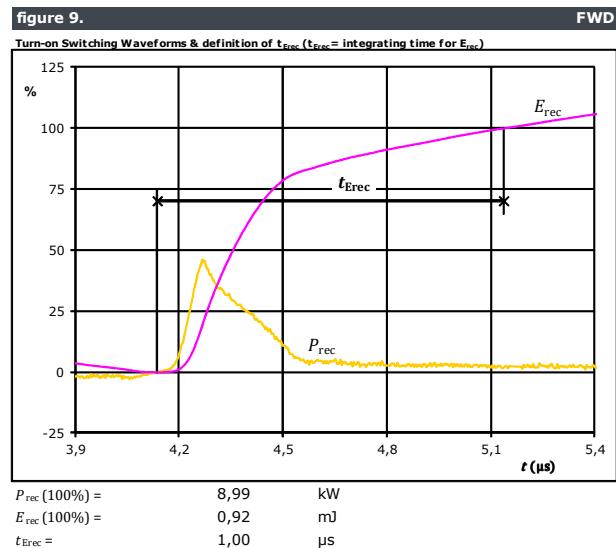
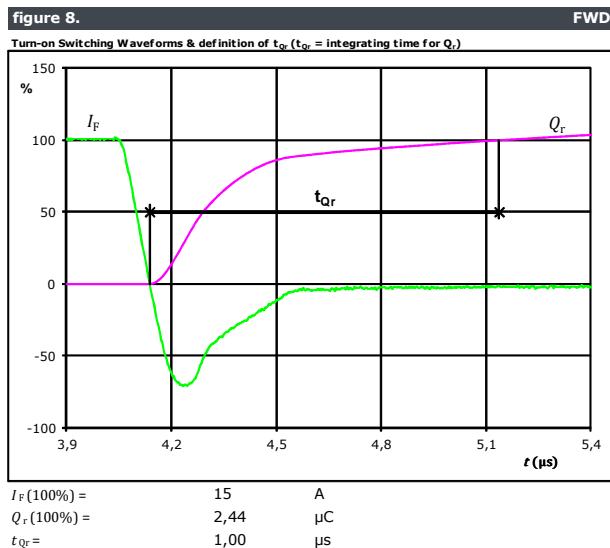
Brake Switching Characteristics





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Brake Switching Characteristics



**10-R112PMA025M7-P630A70**

datasheet

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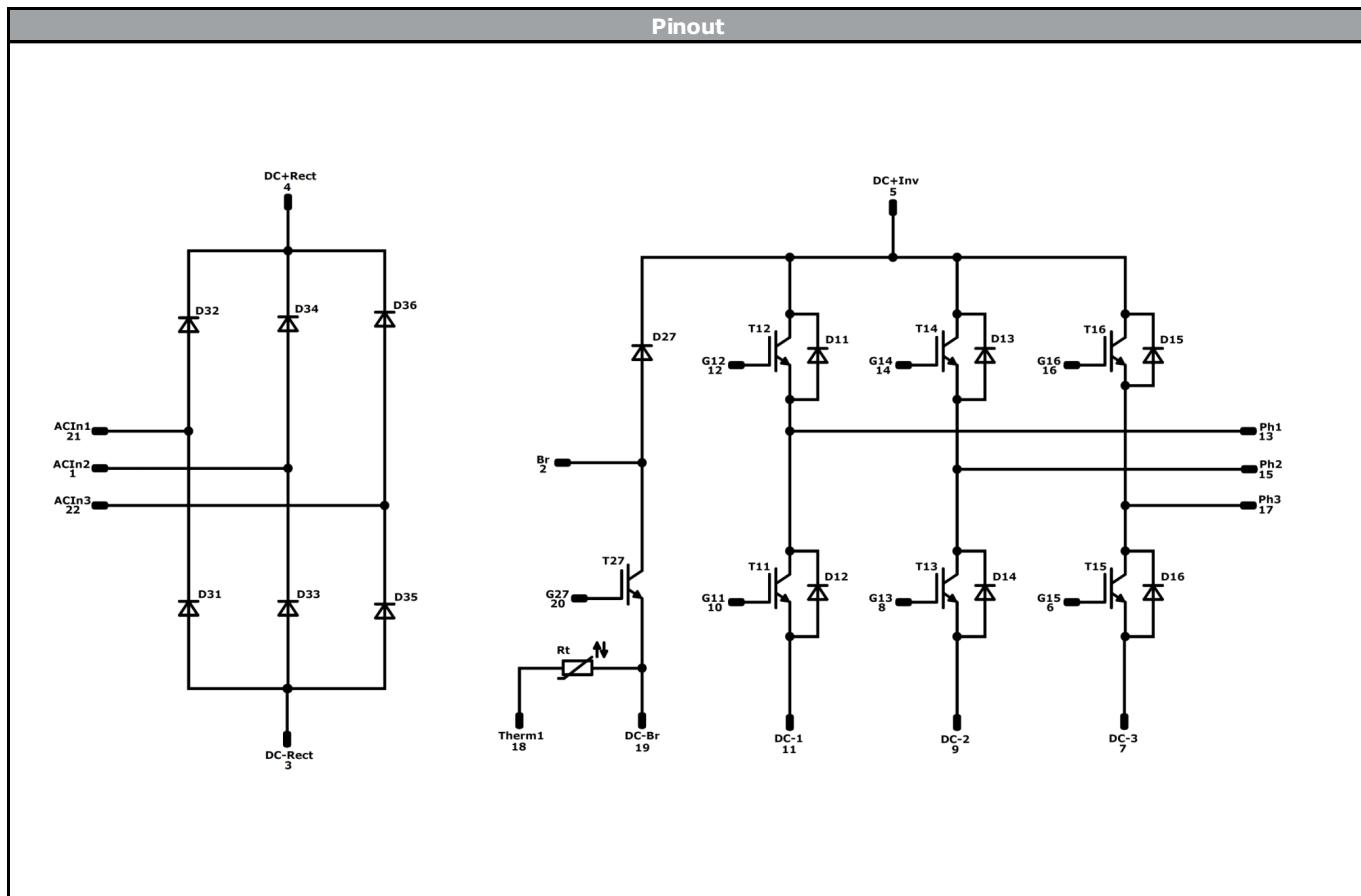
Ordering Code & Marking							
Version				Ordering Code			
without thermal paste with solder pins				10-R112PMA025M7-P630A70			
with thermal paste with solder pins				10-R112PMA025M7-P630A70-/3/			
NN-NNNNNNNNNNNN TTTTTTVVWYY UL VIN LLLL SSSS			Text	Name	Date code	UL & VIN	Lot
				NN-NNNNNNNNNNNN-YYYYWW	WWYY	UL VIN	LLLLL
			Datamatrix	Type&Ver	Lot number	Serial	Date code
				TTTTTTVV	LLLLL	SSSS	WWYY

Outline																																																																																																
Pin table				Outline Drawing																																																																																												
<table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>53</td><td>0</td><td>ACIn2</td></tr><tr><td>2</td><td>46</td><td>0</td><td>Br</td></tr><tr><td>3</td><td>39,5</td><td>0</td><td>DC-Rect</td></tr><tr><td>4</td><td>32,5</td><td>0</td><td>DC+Rect</td></tr><tr><td>5</td><td>28,1</td><td>0</td><td>DC+Inv</td></tr><tr><td>6</td><td>18</td><td>0</td><td>G15</td></tr><tr><td>7</td><td>15</td><td>0</td><td>DC-3</td></tr><tr><td>8</td><td>12</td><td>0</td><td>G13</td></tr><tr><td>9</td><td>9</td><td>0</td><td>DC-2</td></tr><tr><td>10</td><td>3</td><td>0</td><td>G11</td></tr><tr><td>11</td><td>0</td><td>0</td><td>DC-1</td></tr><tr><td>12</td><td>0</td><td>7</td><td>G12</td></tr><tr><td>13</td><td>3</td><td>7</td><td>Ph1</td></tr><tr><td>14</td><td>8,5</td><td>7</td><td>G14</td></tr><tr><td>15</td><td>11,5</td><td>7</td><td>Ph2</td></tr><tr><td>16</td><td>17</td><td>7</td><td>G16</td></tr><tr><td>17</td><td>20</td><td>7</td><td>Ph3</td></tr><tr><td>18</td><td>33</td><td>7</td><td>Therm1</td></tr><tr><td>19</td><td>36</td><td>7</td><td>DC-Br</td></tr><tr><td>20</td><td>39</td><td>7</td><td>G27</td></tr><tr><td>21</td><td>46</td><td>7</td><td>ACIn1</td></tr><tr><td>22</td><td>53</td><td>7</td><td>ACIn3</td></tr></tbody></table>				Pin	X	Y	Function	1	53	0	ACIn2	2	46	0	Br	3	39,5	0	DC-Rect	4	32,5	0	DC+Rect	5	28,1	0	DC+Inv	6	18	0	G15	7	15	0	DC-3	8	12	0	G13	9	9	0	DC-2	10	3	0	G11	11	0	0	DC-1	12	0	7	G12	13	3	7	Ph1	14	8,5	7	G14	15	11,5	7	Ph2	16	17	7	G16	17	20	7	Ph3	18	33	7	Therm1	19	36	7	DC-Br	20	39	7	G27	21	46	7	ACIn1	22	53	7	ACIn3	
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Tolerance of pinpositions: $\pm 0.5\text{mm}$ at the end of pins
Dimension of coordinate axis is only offset without tolerance



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Identification					
ID	Component	Voltage	Current	Function	Comment
D31, D32, D33, D34, D35, D36	Rectifier	1600 V	25 A	Rectifier	
T11, T12, T13, T14, T15, T16	IGBT	1200 V	25 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1200 V	25 A	Inverter Diode	
T27	IGBT	1200 V	15 A	Brake Switch	
D27	FWD	1200 V	15 A	Brake Diode	
Rt	NTC			Thermistor	



10-R112PMA025M7-P630A70

datasheet

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Packaging instruction			
Standard packaging quantity (SPQ) 80	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for flow 90 1 packages see vincotech.com website.			

Package data			
Package data for flow 90 1 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-R112PMA025M7-P630A70-D2-14	18 Feb. 2019	Added thermal paste option to ordering code	30

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.